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L.D. Cooley, P.S. Chang, A.K. Ghosh

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**Superconducting Magnet Division** 

### **Brookhaven National Laboratory**

P.O. Box 5000 Upton, NY 11973-5000 www.bnl.gov

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# Magnetization, RRR and Stability of Nb<sub>3</sub>Sn Strands with High Sub-element Number

L. D. Cooley, P. S. Chang, and A. K. Ghosh

Abstract—The magnetization and low field stability were measured on a series of high current-density Nb<sub>3</sub>Sn strands with 54 to 198 sub-elements taken from accelerator magnet development programs. The effective filament size,  $d_{eff}$ , as determined from the width of the magnetization loop at low field and the extrapolation of the transport critical current from high field, was very close to the sub-element diameter determined by the strand geometry. Self-field corrections were vital for obtaining this agreement; without them,  $d_{eff}$  was overestimated by ~25%. While all strands, even those with  $d_{eff}$  as small as 35  $\mu$ m, exhibited flux-jumps at low field in magnetization measurements, smaller sub-elements produced smaller flux-jump magnitude and a smaller range of field over which flux jumps occurred, suggesting stability improved with decreasing  $d_{eff}$ . However, good combinations of the residual resistivity ratio RRR and the critical current density  $J_c$  became increasingly difficult to obtain by varying the reaction heat treatment as the sub-element number increased. Further analyses of RRR data indicate that tin contamination of the copper stabilizer is underway even before any Nb<sub>3</sub>Sn is formed in strands with high numbers of sub-elements.

Index Terms—Conductivity, Magnetic Field Measurement, Niobium Compounds, Stability, Superconducting Magnets

#### I. INTRODUCTION

Niobium-tin superconducting strands are a core component of accelerator magnet research and development programs. Modern strand designs, such as the "restacked rod process" (RRP) strands considered in this paper from Oxford Instruments–Superconducting Technology [1],[2], attain very high critical current density  $J_c$ , now routinely about 3,000 A mm<sup>-2</sup> in the non-copper area at 12 T field and 4.2 K temperature. To attain such high performance, copper is removed from the sub-element and replaced with Nb and Sn to the highest degree possible. This choice has a side-effect, namely the tendency for the Nb filaments to merge into a single Nb<sub>3</sub>Sn mass during the reaction, which drives up the effective filament diameter  $d_{eff}$  to close to the sub-element diameter  $d_s$ .

Many wire designs, such as those considered in this paper, also use Nb diffusion barriers. In that case, to maximize the area fraction of the strand that is converted to Nb<sub>3</sub>Sn and

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hence maximize the non-copper  $J_c$ , almost full reaction of the Nb diffusion barrier is also intended. This has 2 additional side-effects: (1) the barrier forms a continuous ring of superconducting Nb<sub>3</sub>Sn, which makes  $d_{eff} \approx d_s$  regardless of any filament merging; and (2) the front of diffusing tin is allowed to come dangerously close to the copper stabilizer, often resulting in contamination. These two effects combine in a particularly bad way for the magnet designer, because the large  $d_{eff}$  allows even the slightest disturbance to trigger a flux jump (especially at low fields where  $J_c$  and the stored magnetic energy in the strand is high), which releases heat that cannot escape due to the poor thermal conductivity of Cu-Sn [3]–[6].

A workaround for this situation has been developed recently [4]. By measuring the voltage for a constant applied current while sweeping the field, it is possible to experimentally determine the current density  $J_s$  at which low-field flux-jumps initiate quenches [5]. This stability threshold largely agrees with stability calculations and other observed quench behavior [6].  $J_s$  falls with increasing final reaction time, and its fall is preceded in time by a drop in RRR, which we have suggested is evidence for a dynamic threshold related to heat transfer through tin-contaminated copper [4]. If the reaction parameters are chosen to optimize both RRR and  $J_c$ , then it is possible to maintain  $J_s$  comfortably above  $J_c$ , thus ensuring that the magnet load line never passes through a region of unstable operation.

Although it is possible to build working magnets with this paradigm, open questions remain about the effects of flux-jumps and their recovery on field quality and correction [7]. It is also desirable to simply improve the overall stability of Nb<sub>3</sub>Sn strands, as well as reduce the field errors due to the superconductor magnetization. To this end, new conductors made under the U.S. High-Energy Physics (HEP) Conductor Development Program [8] have contained larger numbers of sub-elements to produce smaller  $d_s$ . The purpose of this paper is to analyze how reducing  $d_s$  affects the stability situation outlined above.

#### II. EXPERIMENT

The RRP strands examined in this study were drawn from inventories at Lawrence Berkeley National Laboratory and Brookhaven National Laboratory, using strands developed explicitly for the Conductor Development Program. The strands and their important parameters are listed in Table I. The subelement designs are very similar for all of the strands except 8079, which had a lower tin fraction than the others. All

L. D. Cooley and A. K. Ghosh are with Brookhaven National Laboratory, PO Box 5000, Upton, NY 11973 USA (e-mail: ldcooley@bnl.gov).

P. S. Chang is a student with the Materials Science Department, State University of New York at Stony Brook. He is supported by a NSF supplemental grant through the MRSEC for Thermal Spray Research.

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TABLE I
SAMPLE PARAMETERS AND EXPERIMENTAL RESULTS

ID	Final HT	R	N	d <sub>s</sub> (µm)	$J_c$ (12T) (A mm <sup>-2</sup> ) <sup>a</sup>	RRR	$J_s$ (A mm <sup>-2</sup> )	$J_M$ (3T) (kA mm <sup>-2</sup> ) <sup>a</sup>	d <sub>eff</sub> (µm)
7054-A	72 h @ 675 °C	1.00	54	67.4	2900	6	1880	19.4	69.5
7054-B	36 h @ 660 °C	1.00	54	67.4	2985	47	3560	18.4	62.5
7054-C	24 h @ 650 °C	1.00	54	67.4	2760	127	4650		
7471-A	100 h @ 665 ℃	0.92	54 <sup>b</sup>	78.6	2290	6	1290		
7471-B	50 h @ 665 °C	0.92	54 <sup>b</sup>	78.6	2120	96	3560	15.2	28.9
8502-B	48 h @ 650 °C	0.79	84	57.1	3050	165	5580	20.8	57.2
8079-A	48 h @ 695 °C	0.70	90	56.6	2680	20	3190		
8079-C	36 h @ 635 ℃	0.70	90	56.6	2330	344	5290	17.5	49.3
8521-B	48 h @ 665 °C	0.91	108	48.7	2830	127	5580		
7904-A	72 h @ 665 °C	0.68	126	48.1	2260	4	1320		
7904-B	72 h @ 635 °C	0.68	126	48.1	2040	9	2310	18.1	45.8
7904-C	36 h @ 635 ℃	0.68	126	48.1	1910	114	5280		
8466-B	48 h @ 650 °C	0.85	198	36.6	2460	12	3783	19.5	38.3

All wires are 0.70 mm diameter except for 7471, which was 0.8 mm diameter.

strands were reacted on stainless steel barrels in a vacuum furnace, as we have described previously [9]. Also, the initial reaction stages were the same for all strands: 48 h @ 210 °C followed by 48 h @ 400 °C, with 50 °C h<sup>-1</sup> ramp rates between soak stages. Because smaller sub-elements provide a shorter length over which tin must diffuse, different final reaction time/temperature combinations were used. These choices, also listed in Table I, were based both on the manufacturer's recommendations and on our past experience. They are separated into 3 categories appended to the billet ID: aggressive (A), which sought to maximize  $J_c$ ; balanced (B), which sought to keep RRR > 40 while still providing high  $J_c$ ; and conservative (C), which was very minimal. The choice of 635 and 665 °C temperatures is based on our empirical observation of approximately double reaction rate for every 15°C temperature rise in the vicinity of 650 °C.

After reserving one turn of each reacted strand for magnetization measurements, the transport critical current measurements followed procedures described previously [9]. An additional length of the strand was soldered in the transition region where the current transfers between the strand and copper current lead. A laser micrometer was used to measure the strand diameter  $d_w$  before reaction, and the copper to non-copper area ratio R was provided by the manufacturer. These were used to determine the non-copper area. Voltage-current (V-I) data were acquired in 0.5 T intervals from 8 T to the 11.5 T limit of our magnet to determine  $J_c$  (criterion:  $10^{-14} \Omega$ -m). This was followed by the acquisition of voltage-field (V-H) data for applied field  $\mu_0 H$  from 0 to 4 T to determine  $J_s$  [5]. The product  $J_c^{0.5}(\mu_0 H)^{0.25}$  produced data that could be fit by a line with a high degree of accuracy (least-squares quality factor > 0.999), which was used to make  $J_c(\mu_0 H)$  extrapolations to the 12 T conductor benchmark field.  $J_c(12T)$  and  $J_s$  are summarized in Table I.

Magnetization measurements were conducted in a commercial SQUID magnetometer at 4.5 K looping between -3 to +5 T. These results are shown in Fig. 1. Short pieces of the strands, approximately 7 mm long and 15 to 20 mg mass, were mounted on nonmagnetic holders such that the field was perpendicular to the strand axis. The sample mass, the density of

copper (8,980 kg m<sup>-3</sup>), and the copper to non-copper area ratio were used to determine the total volume of the sub-elements and convert magnetic moment to magnetization M. The effective filament diameter was then calculated by inverting the critical state equation  $J_M = 3\pi\Delta M \, (4d_{eff})^{-1}$ , where  $\Delta M$  is the full hysteresis at 3 T field and  $J_M$  is the value of the transport critical current density extrapolated to 3 T from the  $J_c^{0.5}(\mu_0 H)^{0.25}$  product fit. A self-field correction was applied to the  $J_c(\mu_0 H)$  data prior to the extrapolation, as discussed later. The  $J_M(3T)$  and  $d_{eff}$  values obtained are listed in Table I.

The sub-element diameter was estimated by using  $d_s = d_w [N(1+R)]^{-1/2}$ , where N is the number of sub-elements. RRR was determined by measuring the ratio of strand resistance at room temperature and at the first onset of normal resistance for warming the strand above the helium bath (~20 K).

#### III. RESULTS AND DISCUSSION

A central question facing advanced Nb<sub>3</sub>Sn conductor development is overcoming the instability issues outlined in the introduction. For many reasons, reducing the sub-element diameter should improve strand stability. Foremost, the reduction of the sub-element diameter should reduce the strand magnetization by the concomitant reduction of  $d_{eff}$ . This is indeed found. Fig. 1 shows that the magnetization hysteresis decreases as N increases. Since  $d_s$  is proportional to  $N^{-1/2}$ , the magnetization is thus decreasing as  $d_s$  decreases. It is noteworthy that billet 8466 achieves the HEP goal [8] of <40  $\mu$ m  $d_{eff}$ . Also, there is progress toward reducing  $d_s$  without compromising performance, as indicated by the excellent results for billets 8502 and 8521.

However, it is not yet possible to eliminate flux-jumps altogether by restacking or dividing sub-elements [3]. Fig. 1 also shows that none of the strands tested were free from flux jumps. Together with the data in Table I, it can be seen that flux jumps are still present above  $\sim 0.5$  T field even for  $d_{eff} < 30$  µm. In V-H data, we often noticed that reproducible flux jumps would occur upon decreasing the field from a higher value at which the wire was stable. This suggests that the flux jumps in the first and fourth quadrants of  $M(\mu_0 H)$  in Fig. 1 give an indication of the onset of instability. To analyze this

<sup>&</sup>lt;sup>a</sup>A self-field correction to the transport data was applied to the 3 T extrapolation but not to the 12 T extrapolation.

<sup>&</sup>lt;sup>b</sup>Each sub-element contained 6 radial columns of Ta filaments to divide the Nb<sub>3</sub>Sn area after reaction. The wire is similar to billet 7261 in [3].

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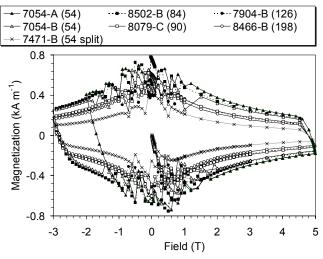


Fig. 1. Magnetization as a function of applied field. Decreases in hysteresis and in the onset field for flux jumps occur as the sub-element number (indicated at the top) increases. Much of the data for 7904-B overlaps the data for 8079-C and 8466-B.

further, in Fig. 2 the (decreasing) field at which such a flux jump occurs is plotted against  $d_{eff}$ . While these data suggest a generally lower flux-jump onset field with smaller  $d_{eff}$ , it is not possible to draw a trend line through these data to predict the effective filament diameter where flux jumps should cease altogether. Part of the problem is that  $J_c$  varies by ~30%, leading to significant scatter in M because  $M \propto J_c d_{eff}$ . For instance, the very conservative sample 8079-C displays the lowest onset field in Fig. 2 due to its weak critical current density.

The effective filament diameter obtained by comparing transport and magnetization data tracks closely with the predicted sub-element diameter based on the strand geometry. This is plotted in Fig. 3. However, large errors can occur when the transport  $J_c$  data is not corrected for self-field prior to extrapolating  $J_c^{0.5}(\mu_0 H)^{0.25}$  to low field to obtain  $J_M$ . To emphasize this point,  $d_{eff}$  values calculated from extrapolating the uncorrected transport  $J_c$  are also shown, which are about 25% higher. These tendencies have been noted previously for Nb-Ti accelerator magnet strands [10], and their presence here verifies the high degree of uniformity of the sub-element cross-sections.

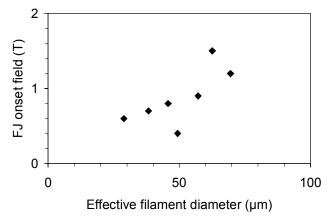


Fig. 2. The field at which flux jumps occur in the first and fourth quadrant of magnetization (Fig. 1), as a function of the effective filament diameter.

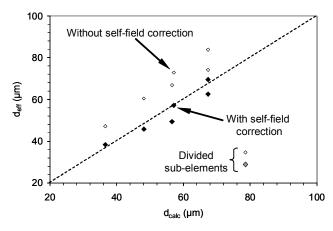


Fig. 3. The effective filament diameter is plotted as a function of the subelement diameter calculated from  $d_w$ , N, and R. Filled symbols represent  $d_{eff}$ calculations using transport  $J_c$  data corrected for self-field, while open symbols represent similar calculations without the self-field correction. Results for billet 7471 with divided sub-elements are also indicated.

One data point in Fig. 3 shows that dividing the subelement can be very useful for reducing the effective filament diameter. The data in Table I (billet 7471) indicates that a compromise of about 25% in performance is required, reducing  $J_c(12T)$  from ~3000 to ~2250 A mm<sup>-2</sup>. This is due to the sub-element area devoted to the dividers. For comparison, Table I also indicates substantially higher  $J_c$  as well as good combinations of  $J_c$  and RRR are available without subdividing the sub-element (especially for billets 8502 and 8521) down to  $d_s \approx 50 \,\mu\text{m}$ . On the other hand, the  $J_c$  data generally display a downward trend with increasing N, suggesting that it becomes more difficult to maintain this performance as  $d_s$  is reduced below 40  $\mu$ m. Thus, there does not seem to be a clear advantage for increasing N further vs. optimizing the divided-subelement approach; both appear to be promising.

Since ductility is more difficult to maintain for larger numbers of restacked sub-elements, loss of conductor uniformity could be offsetting the advantage of utilizing the full subelement area to form superconductor. In particular, thinning or rupture of the diffusion barrier presents a serious obstacle against heat treatment optimization. Although diffusion distances scale with  $d_s$ , a breach of the barrier would open the stabilizer up to contamination even before any Nb<sub>3</sub>Sn is formed. This may explain why several entries in Table I have low RRR values when N>108. Indeed, some evidence for this problem is presented in Fig. 4, which shows a plot of the value of RRR obtained for strands extracted after the first two reaction stages (48 h @ 210°C + 48 h @ 400°C), but before the final stage, versus the number of sub-elements. Although all of the RRR values remain above 250, the  $\sim$ 30% drop as N increases from 54 to 198 suggests that trace contamination is already present in wires with high numbers of sub-elements. An alternative explanation of this trend is electron scattering by the subelements themselves, due to the thickness of the copper between the subelements becoming on the order of the electron mean free path at low temperatures for high N.

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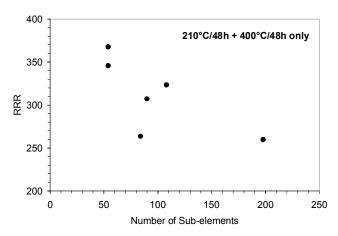


Fig. 4. The residual resistivity ratio is plotted as a function of the number of sub-elements for wire samples extracted prior to the high-temperature stage of the heat treatment, and thus prior to the expected formation of any Nb<sub>3</sub>Sn.

#### IV. CONCLUSION

Significant progress has been made to reduce the strand magnetization, either by reducing the sub-element diameter or by dividing the sub-element. It is now possible to achieve ~3000 A mm<sup>-2</sup> performance in strands with ~100 subelements, while also retaining RRR > 100 and reaching an effective filament diameter of just under 50 µm. Restacks of 198 sub-elements and strands with divided sub-elements both achieve still lower  $d_{eff}$ , but each displayed a significant loss of performance. No strand design examined in this paper produced magnetization curves that were free from flux jumps. Moreover, the data analysis could not predict a clear  $d_{eff}$  value at which flux jumps should disappear. For magnet designers, these trends suggest that significant progress still must be made before flux-jump instabilities are removed, which makes it essential to continue to optimize both  $J_c$  and RRR. Although tin diffusion distances are shorter in strands with smaller subelements, suggesting that reactions can be completed more quickly, evidence was given suggesting the start of tin contamination of the copper stabilizer even before any Nb<sub>3</sub>Sn formed. This suggests that the two-parameter optimization above may be more difficult to attain for strands with smaller sub-elements.

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